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April 12, 2005

From: Daniel W. Roberts

Matter No.: L&G 414284

To:	Company:	Fax Number:	Phone Number:
Examiner Lee	US Patent and Trademark Office	571-273-1785	

Number of Pages Transmitted (including this cover sheet): 8

Message: Application Serial No. 10/758,659
Title: NEW METHOD OF MAKING TOROIDAL MRAM CELLS
HP 200312751-1

Dear Examiner Lee,

Further to your conversation with Brian Short at HP - Palo Alto, we are submitting a replacement copy of the cited article "Zhu, Jian-Gang et al., "Ultrahigh Density Vertical Magnetoresistive Random Access Memory (invited),"Journal of Applied Physics, May 2000, Vol. 87, Number 9, Pages 6668-6673"

I sincerely apologies for the apparent absence of the article and appreciate your time and attention to call with a request for it's replacement. If you should have further questions or concerns please do not hesitate to give me a call.

Thank you
Dan Roberts, 52,172

If you have a problem receiving this facsimile, please call: (816) 292-2000

Fax Attendant: J Price

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PATENT APPLICATION

Sheet 1 of 1

FORM PTO-1449

LIST OF PATENTS AND PUBLICATIONS FOR
APPLICANT'S INFORMATION DISCLOSURE
STATEMENT

(Use several sheets if necessary)

ATTY. DOCKET NO.

200312751-1

APPLICATION NO.

CONFIRMATION NO.

APPLICANT

Manish Sharma

FILING DATE

01/15/2004

GROUP

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	PUBLICATION DATE	NAME	Pages, Columns, Lines Where Relevant Passages or Figures Appear
	1A	5,661,062	Aug 26, 1997	Prinz	
	1B	5,541,868	Jul. 30, 1996	Prinz	
	1C	5,477,482	Dec. 19, 1995	Prinz	
	1D				
	1E				
	1F				
	1G				
	1H				
	1I				
	1J				
	1K				

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	PUBLICATION DATE	NAME OF PATENTEE OR APPLICANT	Pages/Columns/Lines Where Relevant Passages/Figures Appear	Check if Translation attached
	1L					
	1M					
	1N					
	1O					
	1P					

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)

	1Q	Zhu, Jian-Gang et al., "Ultrahigh Density Vertical Magnetoresistive Random Access Memory (invited)," Journal of Applied Physics, May 2000, Vol. 87, Number 9, Pages 6668-6673
	1R	
	1S	

EXAMINER

DATE CONSIDERED

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